WHAT IS CLAIMED IS:

l	1. A process for producing a reaction bonded silicon carbide body, the
2	process comprising:
3	combining a carbon source, silicon carbide, an organic gelation agent and a
4	liquid to form a ceramic slurry;
5	compacting the ceramic slurry into a green body; and
5	exposing the green body to liquid silicon metal to produce a reaction bonded
7	silicon carbide body.

- 2. A process as in claim 1, wherein the carbon source is selected from the group consisting of carbon black and colloidal graphite, and the silicon carbide comprises alpha silicon carbide grit.
- 3. A process as in claim 1, wherein the ceramic slurry includes about 0 wt% to about 20 wt% carbon black, about 0 wt% to about 15 wt% colloidal graphite, about 40 wt% to about 90 wt% alpha silicon carbide grit, about 0.01 wt% to about 15 wt% organic gelation agent and about 10 wt% to about 30 wt% liquid.
- 4. A process as in claim 1, wherein the organic gelation agent is selected from a group consisting of corn starch, potato starch, tapioca starch, wheat starch, methylcellulose, substituted derivatives of methyl-cellulose, carboxy-methyl-cellulose gum, guar gum, sodium alginate, gum arabic, lignosulfonates, polyacrylates, polyvinyl-butyrals and acrylics.
- 5. A process as in claim 1, wherein the ceramic slurry includes about 0.01 wt% to about 5 wt% potato starch as a gelation agent.
- 6. A process as in claim 1, further comprising heating the green body to a temperature of about 1400°C to about 1650°C during siliconization.
 - 7. A process as in claim 1, wherein siliconization comprises exposing the green body to about 20 wt% to 150 wt% (based on green body weight) liquid silicon metal.
- 8. A process as in claim 1, wherein compacting the ceramic slurry comprises forcing the ceramic slurry into a porous mold with a pore size of about 2 microns

- 3 to about 20 microns and applying pressure of about 70 psig to about 600 psig for about 10 4 seconds to about 240 seconds. 9. 1 A process as in claim 1, further comprising agitating the ceramic slurry 2 continuously at low shear for about 4 hours to about 15 hours under vacuum conditions. 1 10. A process as in claim 1, wherein combining further comprises mixing 2 the ceramic slurry for about 10 minutes to about 60 minutes using a high shear, high intensity 3 mixer. 4 11. A process as in claim 1, further comprising drying the green body in a 5. conveyor drying oven at about 30 °C to about 200 °C for about 5 minutes to about 12 minutes. 12. A process as in claim 1, wherein the silicon carbide body comprises an armor torso. A reaction bonded silicon carbide body produced according to the 13. process of claim 1. A body as in claim 13, wherein the silicon carbide body comprises an 14. armor torso. 1 15. A green body, comprising: 2 silicon carbide in a major amount; 3 a carbon source in a moderate amount; 4 an organic gelation agent in a minor amount; and a liquid in a moderate amount. 5 1 16. A body as in claim 15, wherein the carbon source is selected from the group consisting of carbon black and colloidal graphite, and the silicon carbide comprises 2 3 alpha silicon carbide grit. 4 17.
- 17. A body as in claim 15, wherein the green body comprises about 5 wt% to about 17 wt% carbon black, about 3 wt% to about 11 wt% colloidal graphite, about 60 wt% to about 86 wt% alpha silicon carbide grit, about 0.01 wt% to about 17 wt% organic gelation agent and about 5 wt% to about 15 wt% liquid.

1	18. A body as in claim 15, wherein the organic gelation agent is selected
2	from a group consisting of corn starch, potato starch, tapioca starch, wheat starch, methyl-
3.	cellulose, substituted derivatives of methyl-cellulose, carboxy-methyl-cellulose gum, guar
4	gum, sodium alginate, gum arabic, lignosulfonates, polyacrylates, polyvinyl-butyrals and
5	acrylics.
1	19. A body as in claim 18, wherein the green body comprises about
2	0.01 wt% to about 5 wt% potato starch as the organic gelation agent.
1	20. A ceramic slurry for producing a reaction bonded ceramic body, the
2	ceramic slurry comprising:
3	silicon carbide in a major amount;
4	a carbon source in a moderate amount;
-5	an organic gelation agent in a minor amount; and
	a liquid in a moderate amount.
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	21. A ceramic slurry as in claim 20, wherein the carbon source is selected
2	from the group consisting of carbon black and colloidal graphite, and the silicon carbide
3	comprises alpha silicon carbide grit
TJ 1	22. A ceramic slurry as in claim 20, wherein the slurry includes about
	0 wt% to about 20 wt% carbon black, about 0 wt% to about 15 wt% colloidal graphite, about
5	40 wt% to about 90 wt% alpha silicon carbide grit, about 0.01 wt% to about 15 wt% organic
6	gelation agent and about 10 wt% to about 30 wt% liquid.
7	geration agent and about 10 with to about 30 with inquid.
1	23. A ceramic slurry as in claim 20, wherein the organic gelation agent is
2	selected from the group consisting of corn starch, potato starch, tapioca starch, wheat starch,
3	methyl-cellulose, substituted derivatives of methyl-cellulose, carboxy-methyl-cellulose gum,
4	guar gum, sodium alginate, gum arabic, lignosulfonates, polyacrylates, polyvinyl-butyrals
5	and acrylics.
1	24. A ceramic slurry as in claim 23, wherein the ceramic slurry comprises
. 2	about 0.01 wt% to about 5 wt% potato starch as the organic gelation agent.